

2N5087G

2N5087G Information

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Part Number	2N5087G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS PNP 50V 0.05A TO-92
Package	TO-226-3, TO-92-3 (TO-226AA)
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

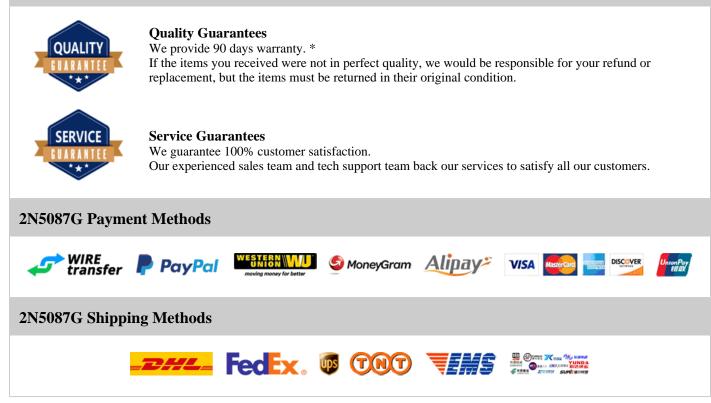
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2N5087G Specifications

Manufacturer Part Number	2N5087G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 (TO-226AA)
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	50mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Current - Collector Cutoff (Max)	50nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	250 @ 100μA, 5V
Power - Max	625mW
Frequency - Transition	40MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Supplier Device Package	TO-92-3
	Report errors?

2N5087G Guarantees



If you have any question about 2N5087G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com